

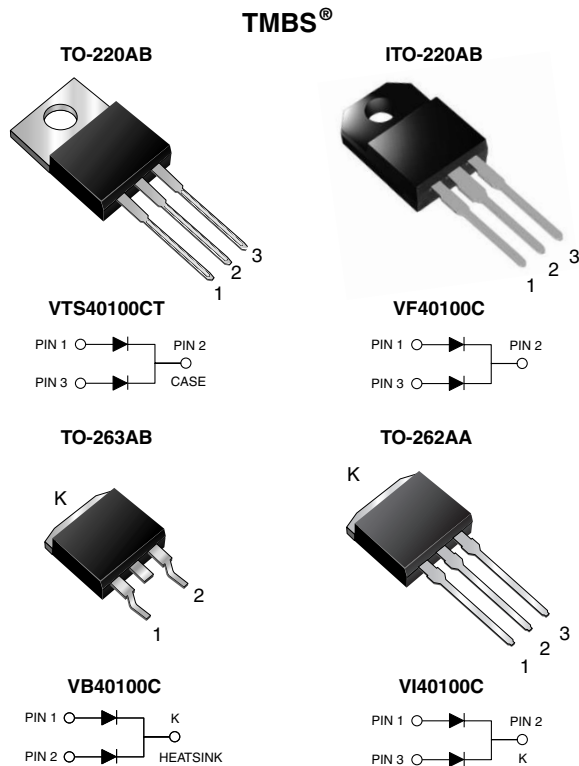


New Product
VTS40100CT, VF40100C, VB40100C & VI40100C

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.375\text{ V}$ at $I_F = 5\text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020C, LF max peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 seconds (for TO-220AB, ITO-220AB & TO-262AA package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, free-wheeling diodes, oring diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB & TO-262AA

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002B and JESD22-B102D

E3 suffix for commercial grade

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 20 A
V_{RRM}	100 V
I_{FSM}	250 A
V_F at $I_F = 20\text{ A}$	0.61 V
T_j max.	150 °C

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VTS40100CT	VF40100C	VB40100C	VI40100C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}		100			V
Maximum average forward rectified current (see Fig. 1)	$I_{F(AV)}$		40 20			A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}		250			A
Isolation voltage (ITO-220AB only) From terminal to heatsink $t = 1\text{ minute}$	V_{AC}		1500			V
Operating junction and storage temperature range	T_J, T_{STG}		- 40 to + 150			°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode ⁽¹⁾	at I _F = 5 A	T _A = 25 °C	V _F	0.463	-	V
	I _F = 10 A			0.535	-	
I _F = 20 A	0.664			0.73		
	at I _F = 5 A	T _A = 125 °C		0.375	-	
	I _F = 10 A			0.445	-	
	I _F = 20 A			0.605	0.67	
Reverse current at rated V _R per diode ⁽²⁾	at V _R = 70 V	T _A = 25 °C	I _R	13.7	-	μA
		T _A = 125 °C		8.4	-	mA
	at V _R = 100 V	T _A = 25 °C		69.6	1000	μA
		T _A = 125 °C		22.5	45	mA

Notes:

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: 10 ms pulse width

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VTS40100CT	VF40100C	VB40100C	VI40100C	UNIT
Typical thermal resistance per diode	R _{θJC}	2.0	4.0	2.0	2.0	°C/W

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	VTS40100CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	VF40100C-E3/45	1.80	45	50/tube	Tube
TO-263AB	VB40100C-E3/4W	1.39	4W	50/tube	Tube
TO-263AB	VB40100C-E3/8W	1.39	8W	800/reel	Tape and reel
TO-262AA	VI40100C-E3/4W	1.46	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

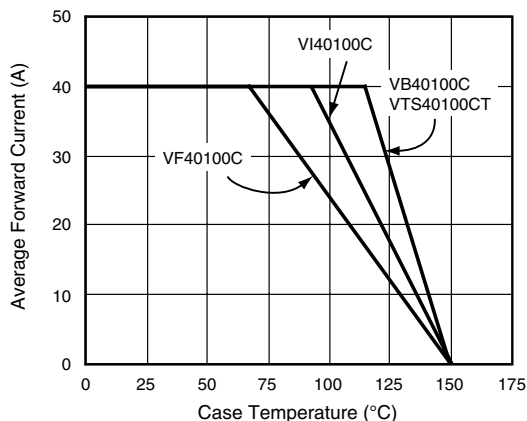


Figure 1. Forward Current Derating Curve

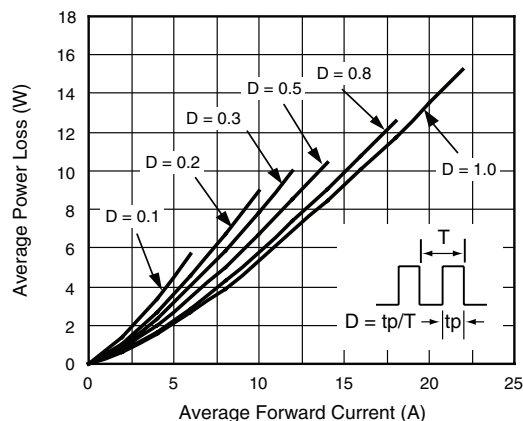


Figure 2. Forward Power Loss Characteristics Per Diode



New Product
VTS40100CT, VF40100C, VB40100C & VI40100C

Vishay General Semiconductor

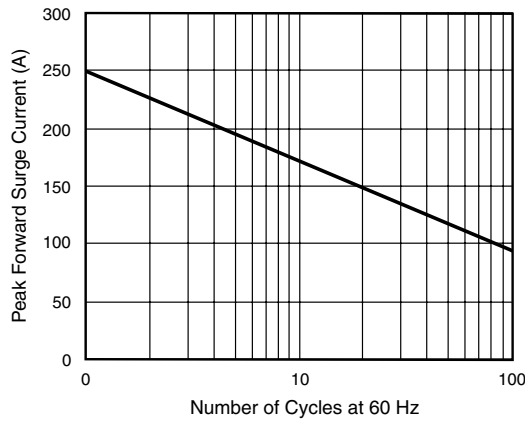


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

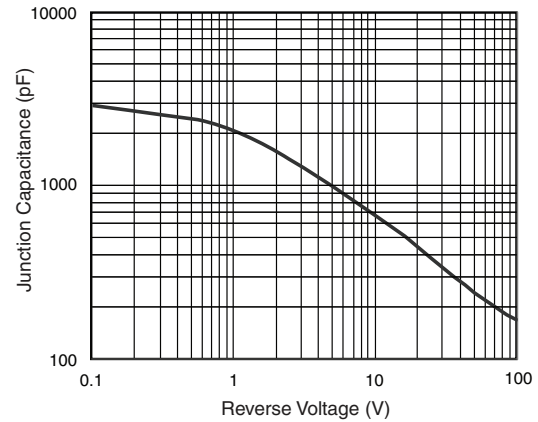


Figure 6. Typical Junction Capacitance Per Diode

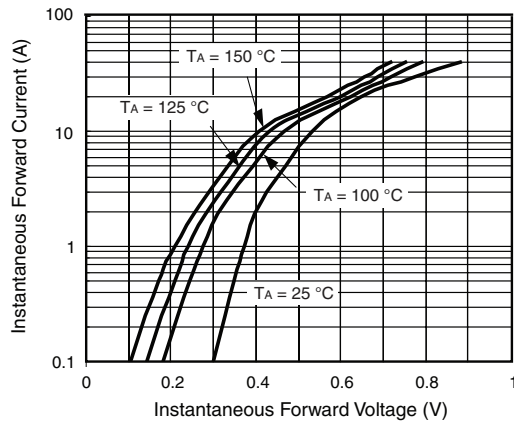


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

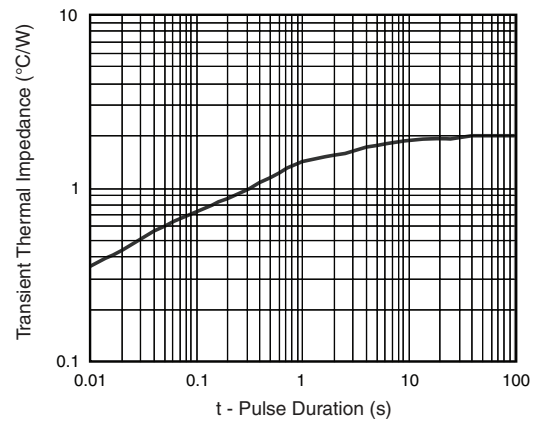


Figure 7. Typical Transient Thermal Impedance Per Diode

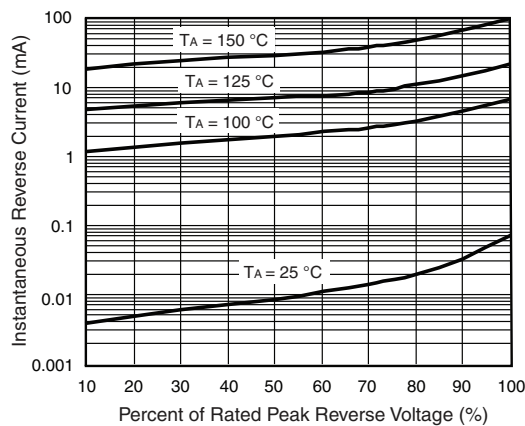
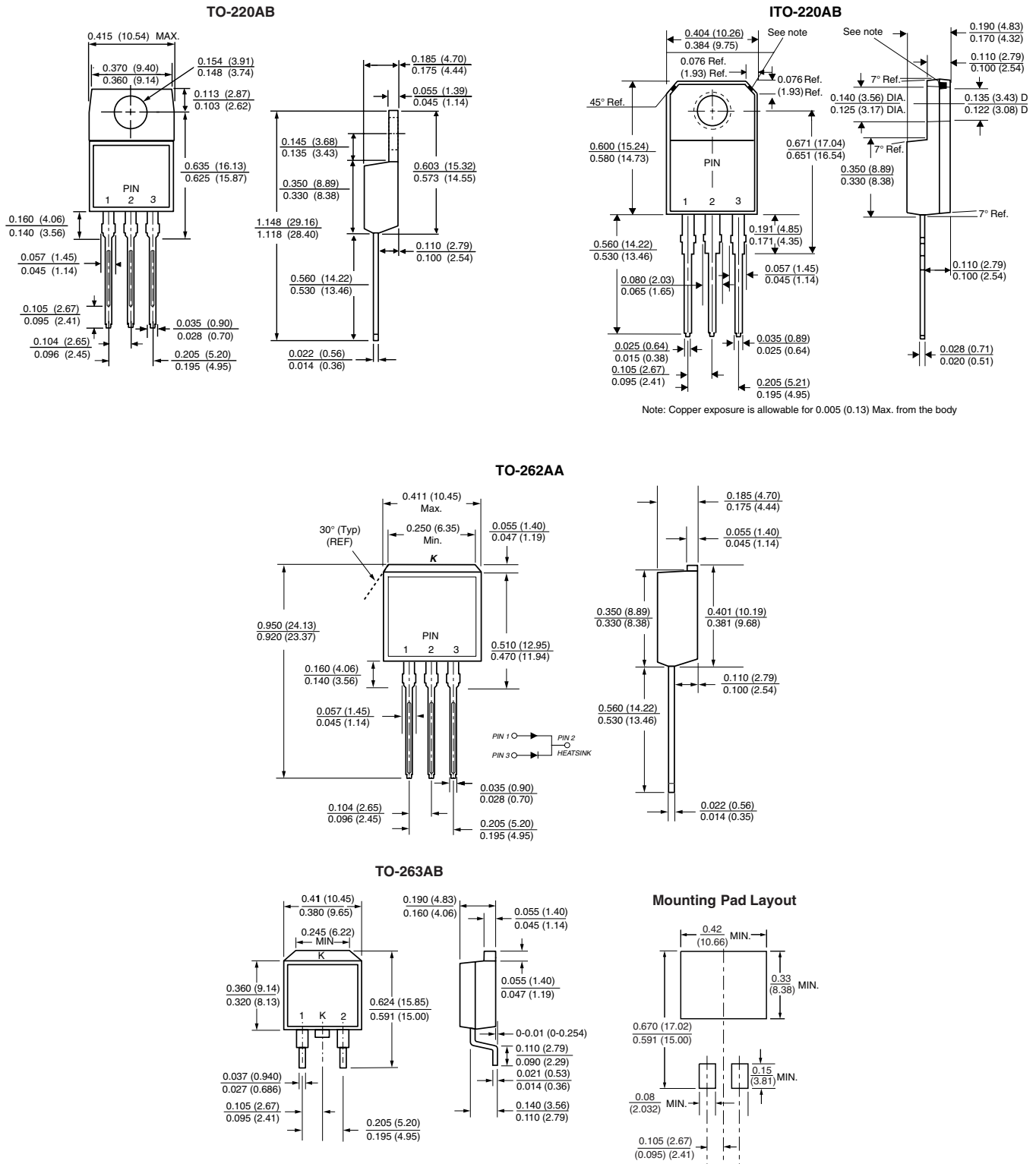


Figure 5. Typical Reverse Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

单击下面可查看定价，库存，交付和生命周期等信息

[>>Vishay\(威世\)](#)